NSN 5961-01-162-4612



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-162-4612 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.300 inches **Overall Width:** 1.050 inches **End Application:** 6130-01-059-6948 **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to emitter voltage/static/base open and 120.0 collector to base voltage, dc and 5.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 50.00 amperes source cutoff current and 125.00 amperes source cutoff current **Power Rating Per Characteristic:** 300.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a

Demilitarization: No

Unit Of Measure:

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